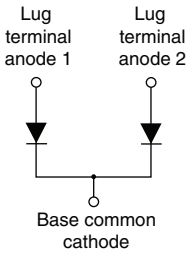
High Performance Schottky Rectifier, 220 A

TO-244



FEATURES

- 150 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

PRODUCT SUMMARY	
$I_{F(AV)}$	220 A
V_R	30 V
Package	TO-244
Circuit	Two diodes common cathodes

DESCRIPTION

The VS-220CNQ.. center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature.
The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	220	A
V_{RRM}		30	V
I_{FSM}	t_p = 5 µs sine	18 000	A
V_F	110 A_{pk}, T_J = 125 °C (per leg)	0.41	V
T_J	Range	-55 to 150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-220CNQ030PbF	UNITS
Maximum DC reverse voltage	V_R	30	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	per leg	$I_{F(AV)}$	50 % duty cycle at T_C = 122 °C, rectangular waveform		110	A
	per device				220	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	18 000	
			10 ms sine or 6 ms rect. pulse		1950	
Non-repetitive avalanche energy per leg		E_{AS}	T_J = 25 °C, I_{AS} = 15 A, L = 1 mH		99	mJ
Repetitive avalanche current per leg		I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		22	A

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forwardvoltage drop per leg See fig. 1	V_{FM} (1)	110 A	T_J = 25 °C	0.49	V
		220 A		0.59	
		110 A	T_J = 125 °C	0.41	
		220 A		0.55	
Maximum reverse leakage current per leg See fig. 2	I_{RM} (1)	T_J = 25 °C	V_R = Rated V_R	10	mA
		T_J = 125 °C		650	
Maximum junction capacitance per leg	C_T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		7400	pF
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}	-55	-	150	°C
Thermal resistance, junction to case	per leg	R_{thJC}	-	-	0.38	°C/W
	per module		-	-	0.19	
Thermal resistance, case to heatsink		R_{thCS}	-	0.10	-	
Weight			-	68	-	g
				2.4		oz.
Mounting torque			35.4 (4)	-	53.1 (6)	lbf · in (N · m)
Mounting torque center hole			30 (3.4)	-	40 (4.6)	
Terminal torque			30 (3.4)	-	44.2 (5)	
Vertical pull			-	-	80	lbf · in
2" lever pull			-	-	35	

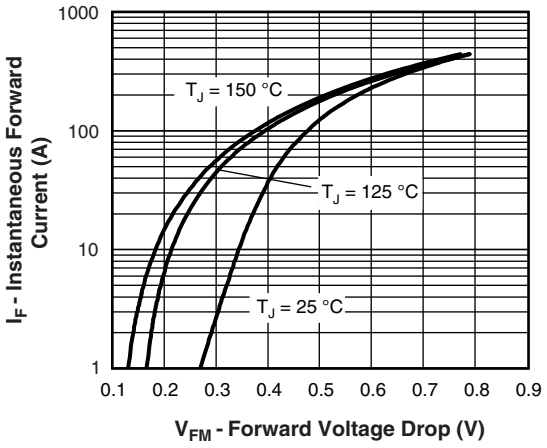


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

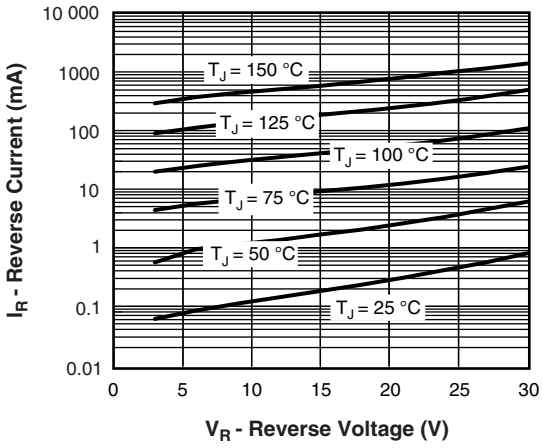


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

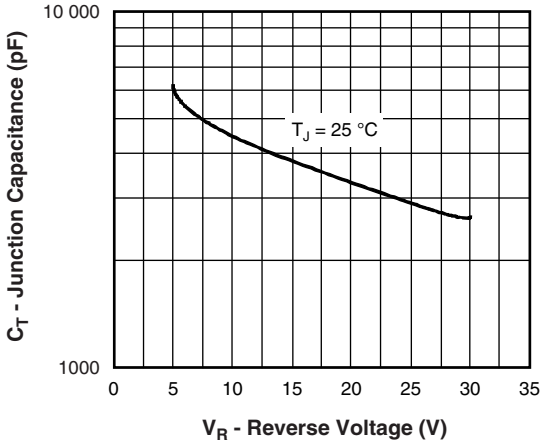


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

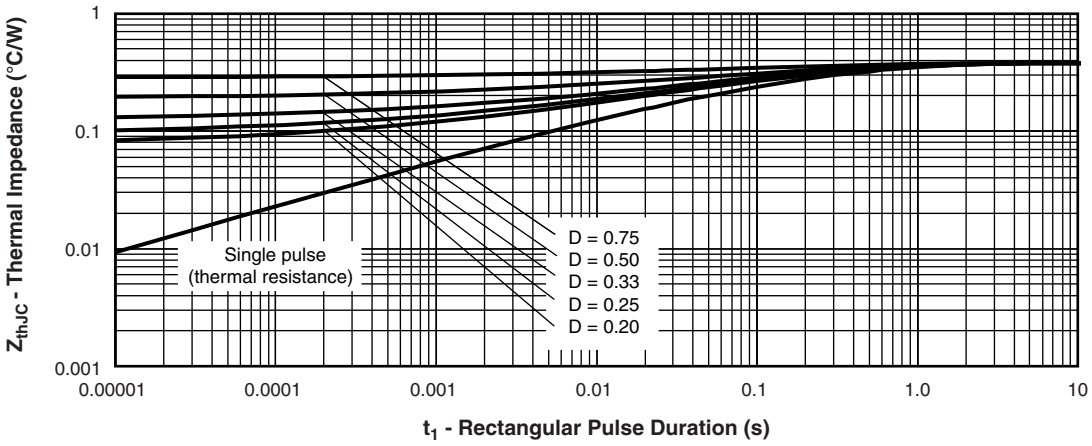


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

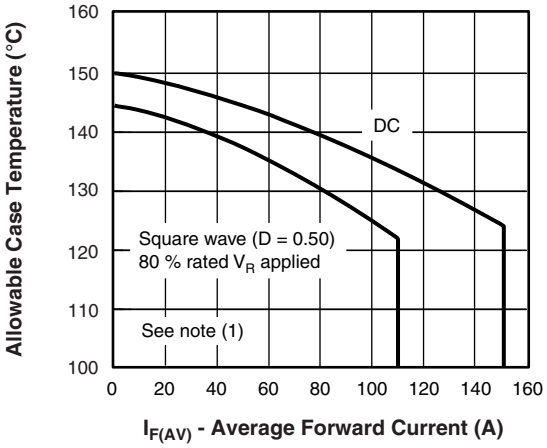


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

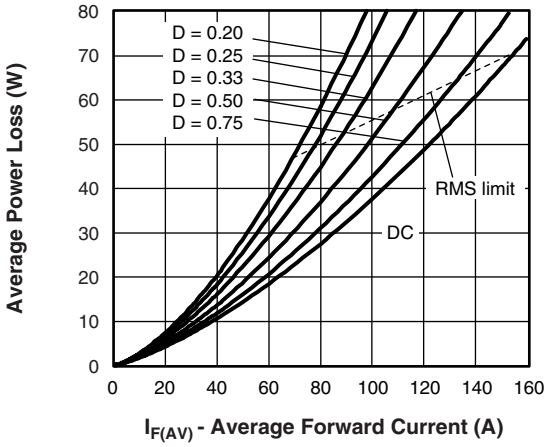


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

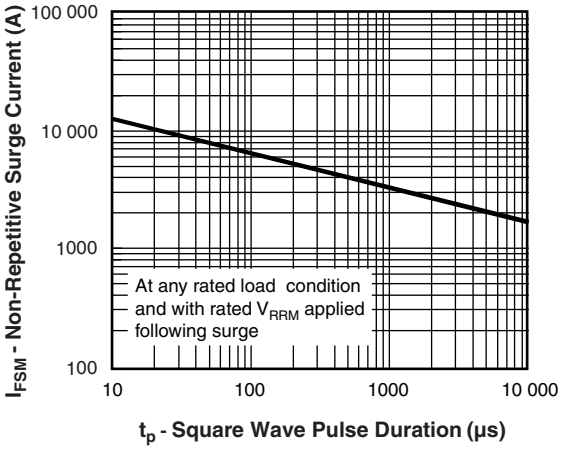


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

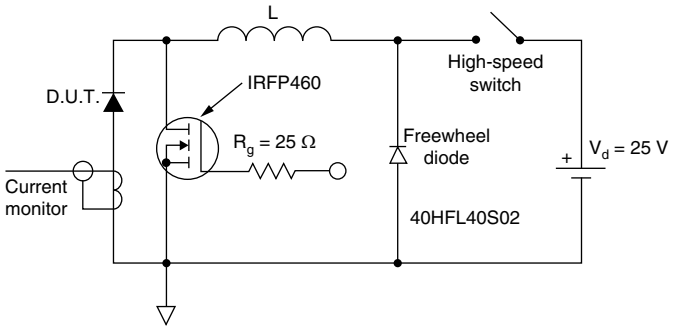


Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE

Device code

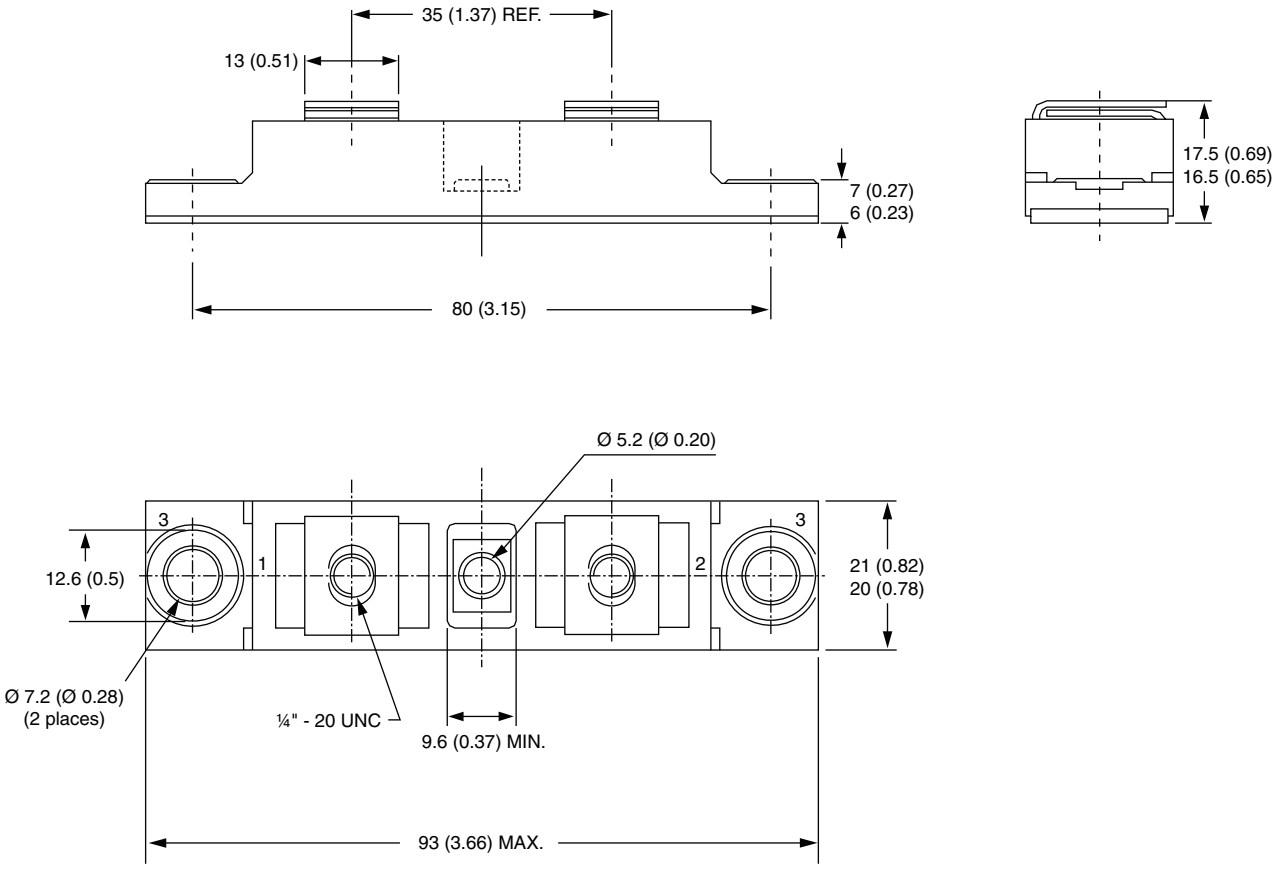
VS-	22	0	C	N	Q	030	PbF
1	2	3	4	5	6	7	8

1	-	Vishay Semiconductors product
2	-	Average current rating (x 10)
3	-	Product silicon identification
4	-	C = Circuit configuration
5	-	N = Not isolated
6	-	Q = Schottky rectifier diode
7	-	Voltage rating (30 V)
8	-	Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95021

TO-244

DIMENSIONS in millimeters (inches)



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